

N-CHANNEL ENHANCEMENT MODE MOSFET
Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$	Package	I_D $T_C = +25^\circ\text{C}$
650V	$V_{GS} = 10\text{V}$	ITO-220AB	9.0A

Description

This new generation complementary dual MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

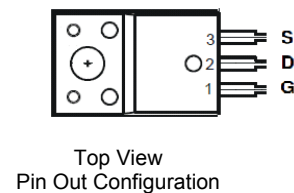
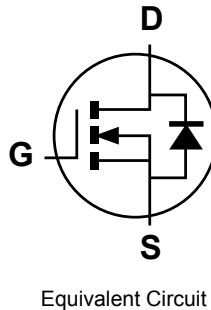
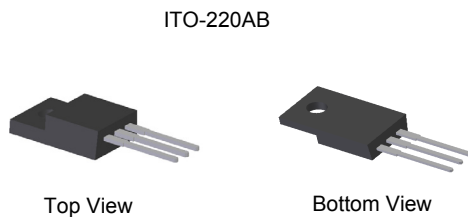
- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

Features

- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- **Lead-Free Finish; RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

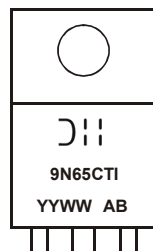
Mechanical Data

- Case: ITO-220AB
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 E3
- Terminal Connections: See Diagram Below
- Weight: ITO-220AB – 1.85 grams (approximate)


Ordering Information (Note 4)

Part Number	Case	Packaging
DMG9N65CTI	ITO-220AB	50 pieces/tube

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information


9N65CTI = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last two digits of year (ex: 13 = 2013)
 WW = Week (01 - 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit	
Drain-Source Voltage			V _{DSS}	650	V	
Gate-Source Voltage			V _{GSS}	±30	V	
Continuous Drain Current (Notes 5 & 6) V _{GS} = 10V	Steady State	T _C = +25°C	I _D	9.0	A	
		T _C = +70°C		7.0		
Pulsed Drain Current (Note 7)			I _{DM}	30	A	
Avalanche Current (Note 8) V _{DD} = 100V, V _{GS} = 10V, L = 60mH			I _{AR}	2.7	A	
Repetitive avalanche energy (Note 8) V _{DD} = 100V, V _{GS} = 10V, L = 60mH			E _{AR}	260	mJ	

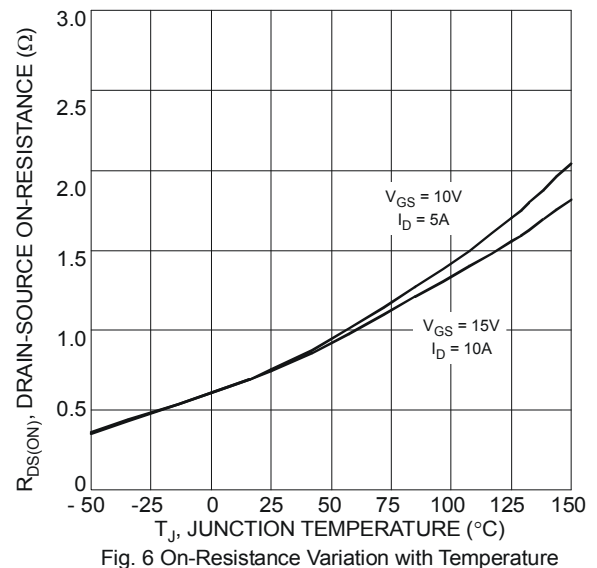
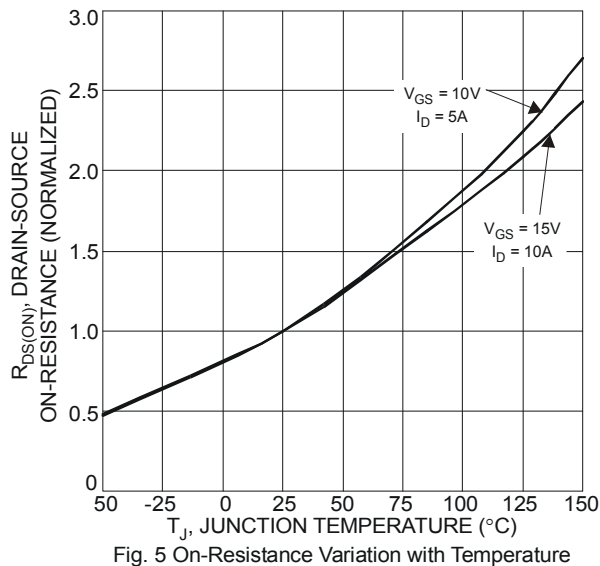
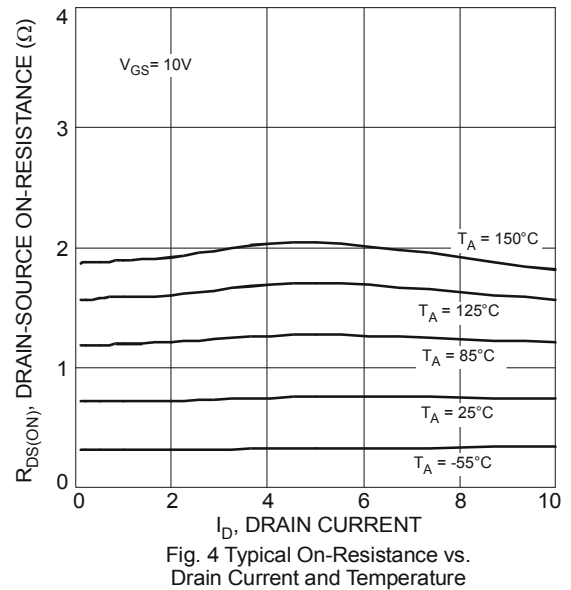
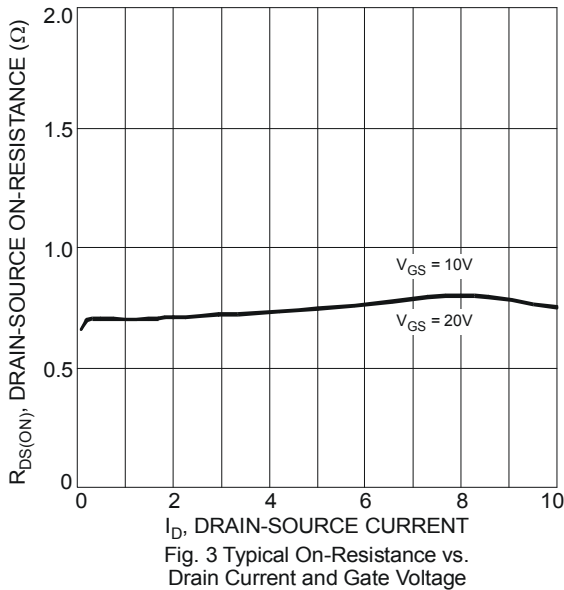
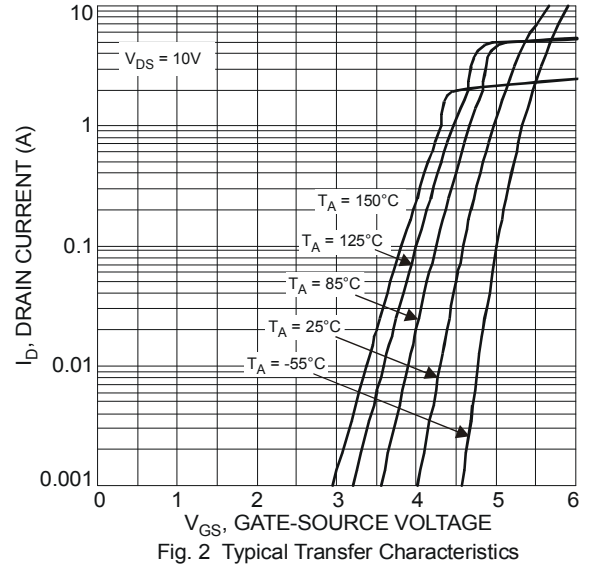
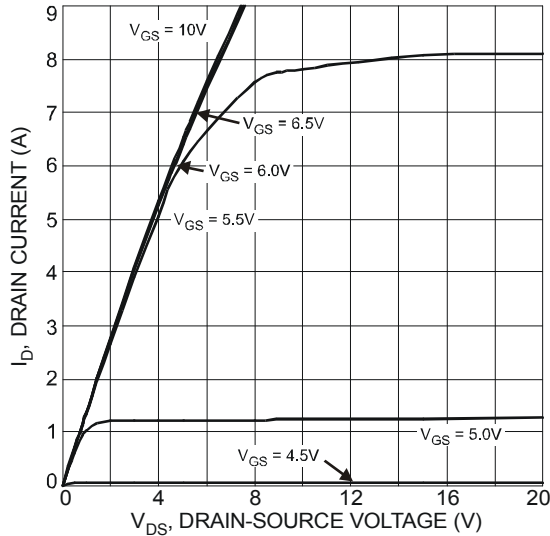
Thermal Characteristics

Characteristic		Symbol	Max	Unit
Power Dissipation (Note 5)	T _C = +25°C	P _D	13	W
	T _C = +70°C		8	
Thermal Resistance, Junction to Case (Note 5)	T _C = +25°C	R _{θJC}	8.84	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV _{DSS}	650	-	-	V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	-	-	1.0	μA	V _{DS} = 650V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	V _{GS} = ±30V, V _{DS} = 0V
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V _{GS(th)}	3	-	5	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	-	0.7	1.3	Ω	V _{GS} = 10V, I _D = 4.5A
Forward Transfer Admittance	Y _{fs}	-	8.5	-	S	V _{DS} = 40V, I _D = 4.5A
Diode Forward Voltage	V _{SD}	-	0.7	1.0	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C _{iSS}	-	2310	-	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	-	122	-		
Reverse Transfer Capacitance	C _{rss}	-	2.2	-		
Gate Resistance	R _g	-	2.2	-	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge V _{GS} = 10V	Q _g	-	39	-	nC	V _{GS} = 10V, V _{DS} = 520V, I _D = 8A
Gate-Source Charge	Q _{gs}	-	8.5	-		
Gate-Drain Charge	Q _{gd}	-	11.9	-		
Turn-On Delay Time	t _{D(on)}	-	39	-	ns	V _{GS} = 10V, V _{DS} = 325V, R _G = 25Ω, I _D = 8A
Turn-On Rise Time	t _r	-	29	-	ns	
Turn-Off Delay Time	t _{D(off)}	-	122	-	ns	
Turn-Off Fall Time	t _f	-	28	-	ns	dI/dt = 100A/μs, V _{DS} = 100V, I _F = 8A
Body Diode Reverse Recovery Time	t _{rr}	-	570	-	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	-	4.17	-	μC	

- Notes:
- Device mounted on an infinite heatsink.
 - Drain current limited by maximum junction temperature.
 - Repetitive rating, pulse width limited by junction temperature.
 - I_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep T_J = +25°C.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to production testing.



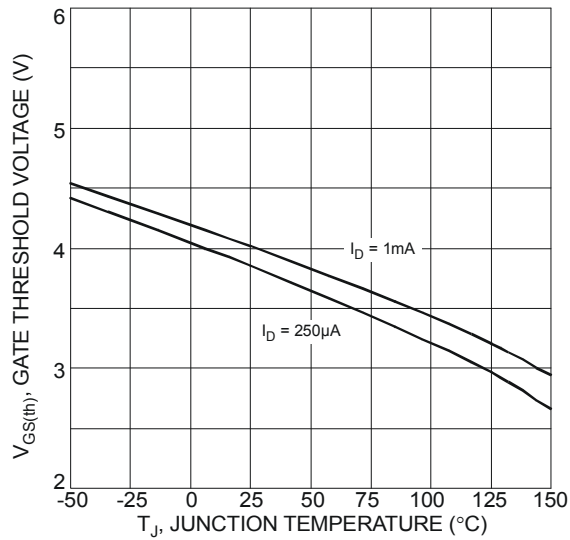


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

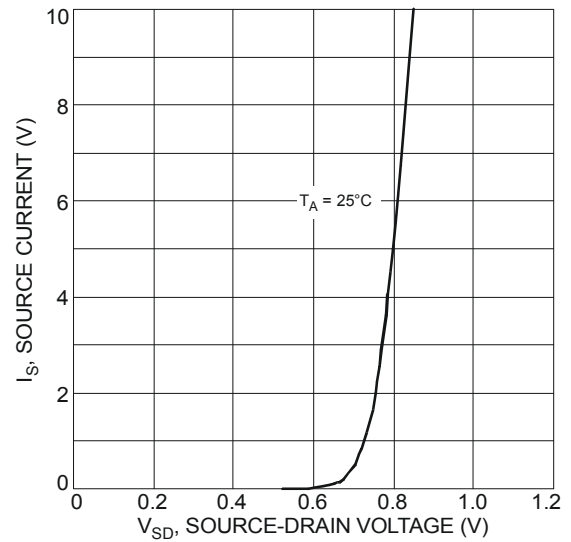
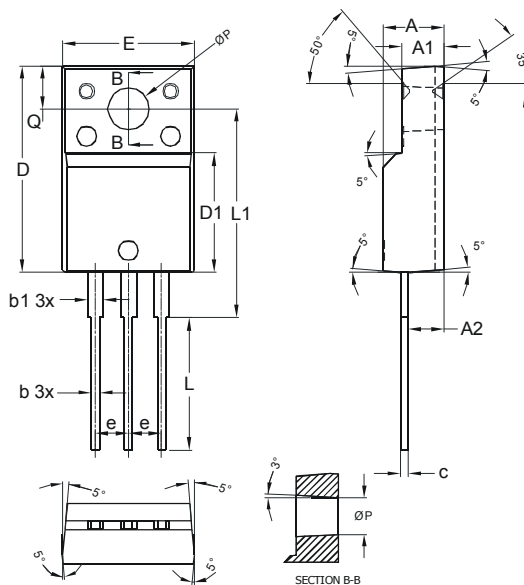


Fig. 8 Diode Forward Voltage vs. Current

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



ITO-220AB			
Dim	Min	Typ	Max
A	4.50	4.70	4.90
A1	3.04	3.24	3.44
A2	2.56	2.76	2.96
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
c	0.50	0.60	0.70
D	15.67	15.87	16.07
D1	8.99	9.19	9.39
e		2.54	
E	9.91	10.11	10.31
L	9.45	9.75	10.05
L1	15.80	16.00	16.20
P	2.98	3.18	3.38
Q	3.10	3.30	3.50
All Dimensions in mm			

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